NSN 5961-01-110-3366

Thyristor Semiconductor Device - Page 1 of 1

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Inclosure Material:
Plastic
Overall Length:
0.420 inches
Overall Height:
0.190 inches
Overall Width:
0.375 inches
Mounting Facility Quantity:
1
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
70.00 amperes forward current, total rms watts
Power Rating Per Characteristic:
2.2 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
Maximum Operating Tempurature Per Measurement Point: 110.0 degrees celsius case
110.0 degrees celsius case
110.0 degrees celsius case Terminal Type And Quantity:
110.0 degrees celsius case Terminal Type And Quantity: 3 pin
110.0 degrees celsius case Terminal Type And Quantity: 3 pin Shelf Life:
110.0 degrees celsius case Terminal Type And Quantity: 3 pin Shelf Life: N/a
110.0 degrees celsius case Terminal Type And Quantity: 3 pin Shelf Life: N/a
110.0 degrees celsius case Terminal Type And Quantity: 3 pin Shelf Life: N/a Unit Of Measure:
110.0 degrees celsius case Terminal Type And Quantity: 3 pin Shelf Life: N/a Unit Of Measure: Demilitarization:
110.0 degrees celsius case Terminal Type And Quantity: 3 pin Shelf Life: N/a Unit Of Measure: Demilitarization: No